

SOD-523 Plastic-Encapsulate Diode

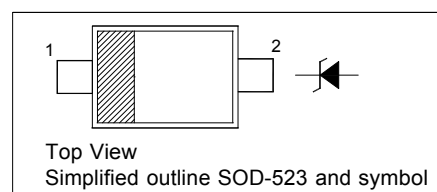
BZX584B2V4-BZX584B39 ZENER DIODE

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

FEATURES

- Planar Die Construction
- 200mW Power Dissipation
- Zener Voltages from 2.4 – 39V



MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Characteristic	Symbol	Value	Unit
Forward Voltage @ $I_F=10\text{mA}$	V_F	0.9	V
Power Dissipation (Note 1)	P_D	200	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	625	$^{\circ}\text{C/W}$
Junction Temperature	T_J	$-55\sim+150$	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	$-55\sim+150$	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

$T_a=25^{\circ}\text{C}$ unless otherwise specified

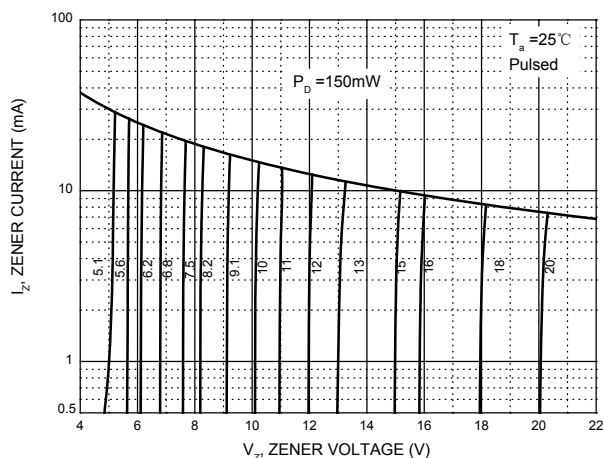
Type Number	Type Code	Zener Voltage Range (Note 2)				Maximum Zener Impedance (Note 3)			Maximum Reverse Current		Typical Temperature Coefficient @ $I_{ZT}=5\text{ mA}$ $\text{mV}/^{\circ}\text{C}$	
		$V_Z@I_{ZT}$			I_{ZT}	$Z_{ZT}@I_{ZT}$	$Z_{ZK}@I_{ZK}$	I_{ZK}	I_R	V_R		
		Nom(V)	Min(V)	Max(V)	mA	Ω		mA	μA	V	Min	Max
BZX584B2V4	2V1	2.4	2.35	2.45	5	100	600	1.0	50	1.0	-3.5	0
BZX584B2V7	2V2	2.7	2.65	2.75	5	100	600	1.0	20	1.0	-3.5	0
BZX584B3V0	2V3	3	2.94	3.06	5	95	600	1.0	10	1.0	-3.5	0
BZX584B3V3	2V4	3.3	3.23	3.37	5	95	600	1.0	5	1.0	-3.5	0
BZX584B3V6	2V5	3.6	3.53	3.67	5	90	600	1.0	5	1.0	-3.5	0
BZX584B3V9	2V6	3.9	3.82	3.98	5	90	600	1.0	3	1.0	-3.5	0
BZX584B4V3	2V7	4.3	4.21	4.39	5	90	600	1.0	3	1.0	-3.5	0
BZX584B4V7	2Z1	4.7	4.61	4.79	5	80	500	1.0	3	2.0	-3.5	0.2
BZX584B5V1	2Z2	5.1	5.00	5.20	5	60	480	1.0	2	2.0	-2.7	1.2
BZX584B5V6	2Z3	5.6	5.49	5.71	5	40	400	1.0	1	2.0	-2.0	2.5
BZX584B6V2	2Z4	6.2	6.08	6.32	5	10	150	1.0	3	4.0	0.4	3.7
BZX584B6V8	2Z5	6.8	6.66	6.94	5	15	80	1.0	2	4.0	1.2	4.5
BZX584B7V5	2Z6	7.5	7.35	7.65	5	15	80	1.0	1	5.0	2.5	5.3
BZX584B8V2	2Z7	8.2	8.04	8.36	5	15	80	1.0	0.7	5.0	3.2	6.2
BZX584B9V1	2Z8	9.1	8.92	9.28	5	15	100	1.0	0.5	6.0	3.8	7.0
BZX584B10	2Z9	10	9.80	10.20	5	20	150	1.0	0.2	7.0	4.5	8.0
BZX584B11	2Y1	11	10.78	11.22	5	20	150	1.0	0.1	8.0	5.4	9.0
BZX584B12	2Y2	12	11.76	12.24	5	25	150	1.0	0.1	8.0	6.0	10.0
BZX584B13	2Y3	13	12.74	13.26	5	30	170	1.0	0.1	8.0	7.0	11.0
BZX584B15	2Y4	15	14.70	15.30	5	30	200	1.0	0.1	10.5	9.2	13.0
BZX584B16	2Y5	16	15.68	16.32	5	40	200	1.0	0.1	11.2	10.4	14.0
BZX584B18	2Y6	18	17.64	18.36	5	45	225	1.0	0.1	12.6	12.4	16.0
BZX584B20	2Y7	20	19.60	20.40	5	55	225	1.0	0.1	14.0	14.4	18.0
BZX584B22	2Y8	22	21.56	22.44	5	55	250	1.0	0.1	15.4	16.4	20.0
BZX584B24	2Y9	24	23.52	24.48	5	70	250	1.0	0.1	16.8	18.4	22.0
BZX584B27	2X1	27	26.46	27.54	2	80	300	0.5	0.1	18.9	21.4	25.3
BZX584B30	2X2	30	29.40	30.60	2	80	300	0.5	0.1	21.0	24.4	29.4
BZX584B33	2X3	33	32.34	33.66	2	80	325	0.5	0.1	23.1	27.4	33.4
BZX584B36	2X4	36	35.28	36.72	2	90	350	0.5	0.1	25.2	30.4	37.4
BZX584B39	2X5	39	38.22	39.78	2	130	350	0.5	0.1	27.3	33.4	41.2

Notes:

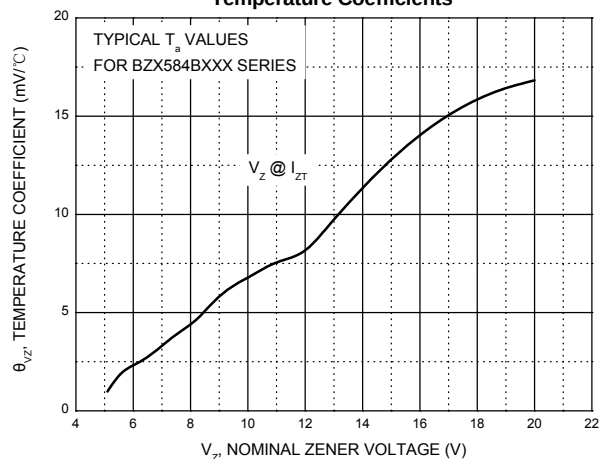
1. Valid provided that device terminals are kept at ambient temperature.
2. Tested with pulses, period=5ms,pulse width =300 μs .
3. $f=1\text{kHz}$.

Typical Characteristics

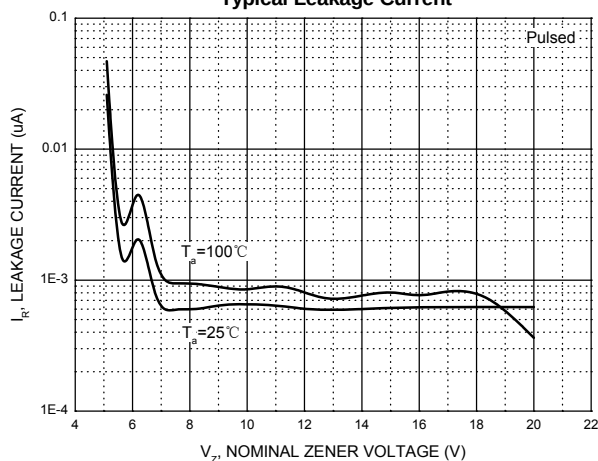
Zener Characteristics (V_Z 5.1V to 20 V)



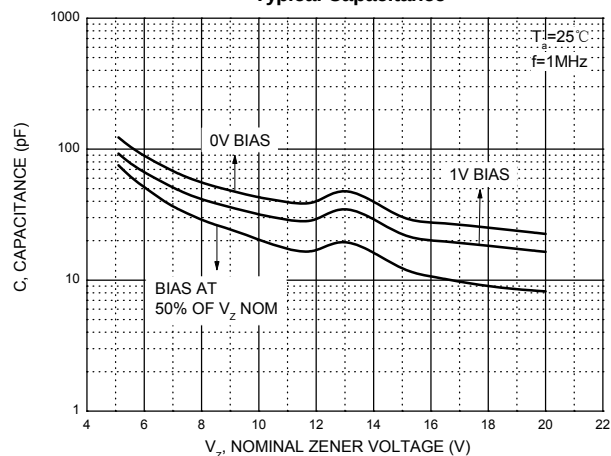
Temperature Coefficients



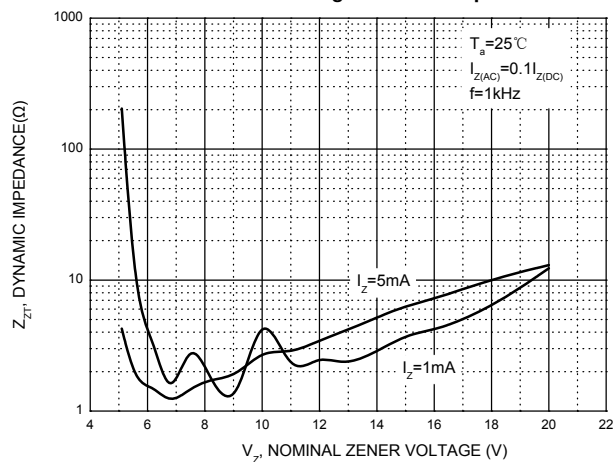
Typical Leakage Current



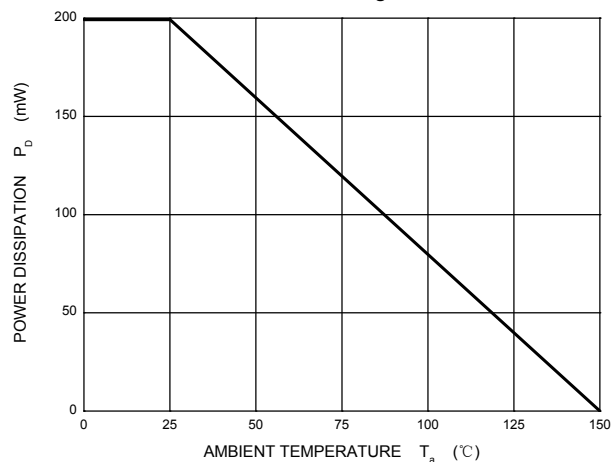
Typical Capacitance



Effect of Zener Voltage on Zener Impedance



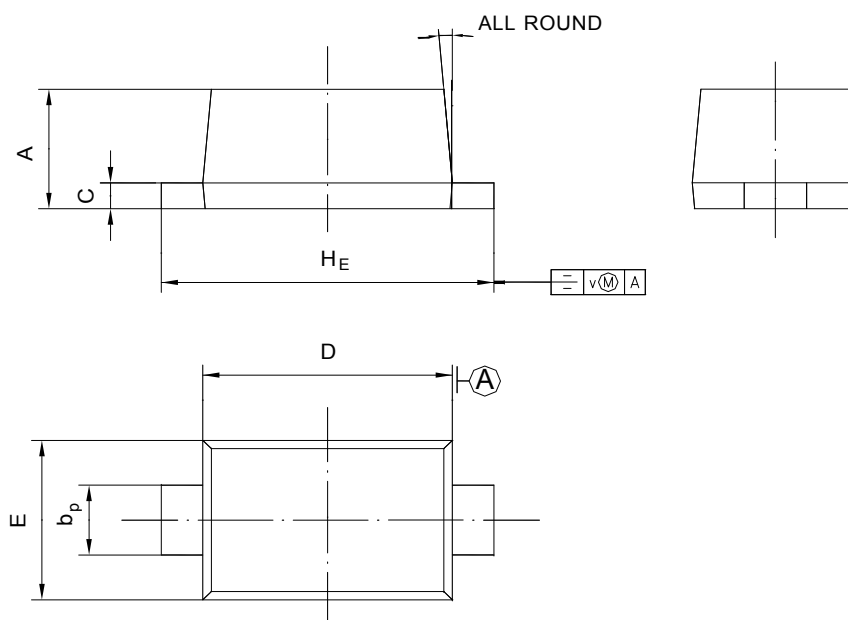
Power Derating Curve



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.77 0.51	0.40 0.25	0.15 0.08	1.30 1.10	0.85 0.75	1.7 1.5	0.1	5°